

# Total Ionization Dose (TID) Test Results of the RH117H Positive Adjustable Regulator @ High Dose Rate (HDR)

HDR = 50 rads(Si)/s

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## Acknowledgements

The authors would like to thank the Product Engineering and Design S-Power groups from Linear Technology for their help with the board design and assembly as well as the data collection pre- and post-irradiations. Special thanks are also for Thomas Shepherd from Defense Microelectronics Activity (DMEA) for the extensive work for board setup and continuous dosimetry monitoring throughout the tests.



## TID HDR Testing of the RH117H Positive Adjustable Regulator

Part Type Tested: RH117H Positive Adjustable Regulator

**Traceability Information:** Fab Lot # W10905063.1; Assembly Lot # 755614; Wafer #10. See photograph of unit under test in Appendix A.

**Quantity of Units:** 42 units received, 2 units for control, 20 units for biased irradiation, and 20 units for unbiased irradiation. Serial numbers 726-729, 735-739, 745-749, and 755-759 had all pins tied to ground during irradiation. Serial numbers 730-734, 740-744, 750-754, and 760-764 were biased during irradiation. Serial numbers 723 and 724 were used as control. See Appendix B for the radiation bias connection tables.

Radiation and Electrical Test Increments: 40 samples were divided into four groups of 10 each. Serial numbers 725-734 of group 1 were irradiated to 10 Krads(Si). Serial numbers 735-744 of group 2 were irradiated to 20 Krads(Si). Serial numbers 745-754 of group 3 were irradiated to 50 Krads(Si). Serial numbers 755-764 of group 4 were irradiated to 100 Krads(Si).

Radiation dose: 50 rads(Si)/sec.

Radiation Test Standard: MIL-STD-883 TM1019.9 Condition A.

**Test Hardware and Software:** LTX pre- and post-irradiation test program EQ2CR117H.01.

Facility and Radiation Source: Defense Micro Electronic Activity (DMEA) and Cobalt-60.

**Irradiation and Test Temperature:** Room temperature controlled to 24°C±6°C per MIL-STD-883 and MIL-STD-750.

## SUMMARY

ALL 42 PARTS PASSED THE ELECTRICAL TEST LIMITS AS SPECIFIED IN THE DATASHEET AFTER EACH IRRADIATION INCREMENT. ADDITIONAL INFORMATION CAN BE PROVIDED PER REQUEST.



## 1.0 Overview and Background

Among other radiation effects, Total Ionizing Dose (TID) may affect electrical characteristics, causing parametric and/or functional failures in integrated circuits. During gamma-irradiations, TID-induced and transported electron-hole pairs may result in charge trapping in a transistor's dielectrics and interface regions, affecting the device's basic features. Such effects warrant testing and monitoring of circuits to TID, after which annealing and/or Time Dependent Effects (TDE) may take place, depending on the circuit's design and process technology. Hence the requirement per Condition A (for high-dose rates ranging from 50 and 300 rads(Si)/sec) in TM1019, MIL-STD-883 is to not exceed the allowed time of one hour from the end of an incremented irradiation and an electrical test. Additionally, the total time from the end of one incremental irradiation to the start of the next incremental step should be less than two hours.

## 2.0 Radiation Facility and Test Equipment

The samples were irradiated at Defense Micro-Electronics Activity (DMEA) facility in Sacramento, California. DMEA utilizes J.L. Shepherd model 81-22/484 to provide the dose-rate of 50 rads(Si)/s. A special design screw-driven automatic cart inside the exposure tunnel positions the Device-Under-Test (DUT) precisely and repeatedly from the source to attain optimal rate verified by ion chamber detectors. See Appendix C for the certificate of dosimetry.

#### 3.0 Test Conditions

The 40 test samples and two control units were electrically tested at 25°C prior to irradiation. The parts were then placed in a lead/aluminum container and aligned with the radiation source, Cobalt-60, at DMEA facility in Sacramento, California. During irradiation, five units of six separate groups were biased at +/- 15V and other five of similar groups had all pads grounded. Ten units of group 1 were irradiated to 10 Krads(Si); group 2 to 20 Krads(Si); group 3 to 50 Krads(Si); and group 4 to 100 Krads(Si). After irradiation, the samples were transported in dry ice to Linear Technology testing facility. Testing was performed on the two control units to confirm the operation of the test system prior to the electrical testing of the 42 units (40 irradiated and 2 control).

The criteria to pass the high dose-rate test is that five samples in each corresponding dose group irradiated under electrical bias must pass the datasheet limits. If any of the tested parameters of these five units of each group do not meet the required limits then a failure-analysis of the part should be conducted and if valid the lot will be scrapped.



#### 4.0 Tested Parameters

The following parameters were measured pre- and post-irradiations:

- $V_{REF}(V)$  @  $10mA \le I_{OUT} \le I_{MAX}$ ,  $3V \le (V_{IN} V_{OUT}) \le 40V$
- Line Regulation (%/V) @  $I_{LOAD} = 10$ mA,  $3V \le (V_{IN} V_{OUT}) \le 40$ V
- Load Regulation (mV) @ V<sub>OUT</sub> ≤ 5V, 10mA ≤ I<sub>OUT</sub> ≤ I<sub>MAX</sub>
- Load Regulation (%) @ V<sub>OUT</sub> ≥ 5V, 10mA ≤ I<sub>OUT</sub> ≤ I<sub>MAX</sub>
- Adjust Pin Current (uA)
- Adjust Pin Current Change (uA) @ 10mA ≤ I<sub>OUT</sub> ≤ I<sub>MAX</sub>
- Adjust Pin Current Change (uA) @ 3V ≤ (V<sub>IN</sub> V<sub>OUT</sub>) ≤ 40V
- Minimum Load Current (mA) @ (V<sub>IN</sub> − V<sub>OUT</sub>) = 40V
- Current Limit (A) @  $(V_{IN} V_{OUT}) \le 5V$
- Current Limit (A) @  $(V_{IN} V_{OUT}) = 40V$

Appendix D details the test conditions, minimum and maximum values at different accumulated doses.



#### 5.0 Test Results

All 40 samples passed the post-irradiation electrical tests. All measurements of the ten listed parameters in section 4.0 are within the specification limits.

The used statistics in this report are based on the tolerance limits, which are bounds to gage the quality of the manufactured products. It assumes that if the quality of the items is normally distributed with known mean and known standard deviation, the two-sided tolerance limits can be calculated as follows:

 $+K_{TL} = mean + (K_{TL})$  (standard deviation)

 $-K_{TL}$  = mean -  $(K_{TL})$  (standard deviation)

Where  $+K_{TL}$  is the upper tolerance limit and  $-K_{TL}$  is the lower tolerance limit. These tolerance limits are defined in a table of inverse normal probability distribution.

However, in most cases, mean and standard deviations are unknown and therefore it is practical to estimate both of them from a sample. Hence the tolerance limit depends greatly on the sample size. The Ps90%/90%  $K_{TL}$  factor for a lot quality P of 0.9, confidence C of 0.9 with a sample size of 5, can be found from the tabulated table (MIL-HDBK-814, page 94, table IX-B). The  $K_{TL}$  factor in this report is 2.742.

In the plots, the dotted lines with diamond markers are the average of the measured data points of five samples irradiated under electrical bias while the dashed lines with X-markers are the average of measured data points of five units irradiated with all pins tied to ground. The solid lines with triangle markers are the 90%/90% minimum and maximum determined from the calculation of the  $K_{TL}$  on the samples irradiated in the biased setup. The solid lines with square symbols are the 90%/90% minimum and maximum determined from the calculation of the  $K_{TL}$  on the five samples irradiated with all pins grounded. The orange solid lines with circle markers are the specification limits.



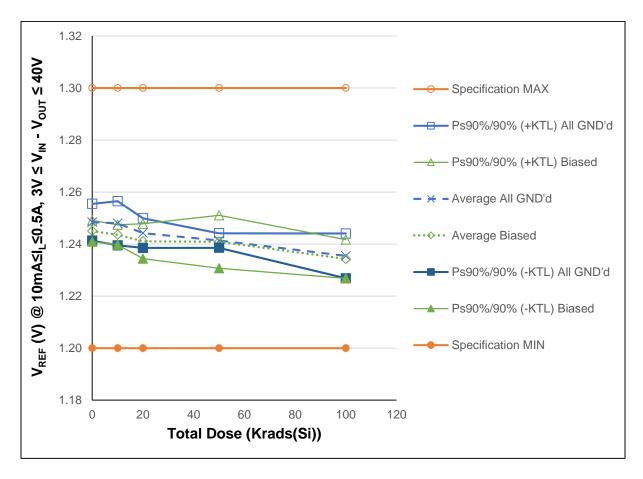


Figure 5.1 Plot of V<sub>REF</sub> versus Total Dose



Table 5.1: Raw data for reference voltage versus total dose including the statistical calculations, minimum specification, maximum specification, and the status of the test (PASS/FAIL) under the

orange headers)

range head	ders)					
Parameter	$V_{RFF}$ @ $I_{I}$ =0.01 to 0.5A, 3V to 40V	7	Total Dose (	Krads(Si)) @	9 50rads/se	C
Units	(V)	0	10	20	50	100
725	All GND'd Irradiation	1.25050	1.25030			
726		1.24620	1.24495			
727		1.24525	1.24431			
728		1.25104	1.25070			
729		1.24906	1.24969			
730		1.24451	1.24307			
731	Biased Irradiation	1.24272	1.24156			
732		1.24598	1.24495			
733		1.24525	1.24347			
734	Biased Irradiation	1.24658	1.24490			
735		1.24573	112 1 100	1.24490		
736		1.24608		1.24523		
737	All GND'd Irradiation	1.24672		1.24553		
738		1.24231		1.24053		
739		1.24449		1.24484		
740		1.24390		1.24156		
741	Biased Irradiation	1.24253		1.23920		
742	Biased Irradiation	1.24560		1.24368		
743	Biased Irradiation	1.23987		1.23798		
744	Biased Irradiation	1.24520		1.24301		
745		1.24421		1.2 1001	1.24185	
746		1.24445			1.24155	
747	All GND'd Irradiation	1.24475			1.24216	
748		1.24276			1.23958	
749		1.24398			1.24164	
750		1.24983			1.24319	
751	Biased Irradiation	1.24540			1.24116	
752	Biased Irradiation	1.24153			1.23443	
753		1.24727			1.24324	
754	Biased Irradiation	1.24636			1.24248	
755		1.24032			112 12 10	1.23065
756		1.24571				1.23668
757	All GND'd Irradiation	1.24672				1.23758
758		1.24689				1.23834
759		1.24336				1.23401
760		1.24374				1.23119
761	Biased Irradiation	1.24266				1.23224
762	Biased Irradiation	1.24764				1.23758
763		1.24414				1.23396
764		1.24672				1.23645
723	i	1.25226	1.25305	1.25305	1.25305	1.25305
724		1.24825	1.24847	1.24847	1.24847	1.24847
	All GND'd Irradiation Statistics		_	_		_
	Average All GND'd	1.24841	1.24799	1.24421	1.24135	1.23545
	Std Dev All GND'd	0.00258	0.00310	0.00208	0.00102	0.00314
	Ps90%/90% (+KTL) All GND'd	1.25548	1.25648	1.24990	1.24415	1.24407
	Ps90%/90% (-KTL) All GND'd	1.24134	1.23950	1.23851	1.23856	1.22683
	Biased Irradiation Statistics					
	Average Biased	1.24501	1.24359	1.24109	1.24090	1.23429
	Std Dev Biased	0.00150	0.00141	0.00244	0.00371	0.00271
	Ps90%/90% (+KTL) Biased	1.24911	1.24746	1.24779	1.25108	1.24172
	Ps90%/90% (-KTL) Biased	1.24091	1.23972	1.23439	1.23072	1.22685
	Specification MIN	1.20	1.20	1.20	1.20	1.20
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Specification MAX	1.30	1.30	1.30	1.30	1.30
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	( included in the control of the con		00	00	00	
	Status (-KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
			00	00	00	
	Status (-KTL) Biased	PASS	PASS	PASS	PASS	PASS
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS
-	,					



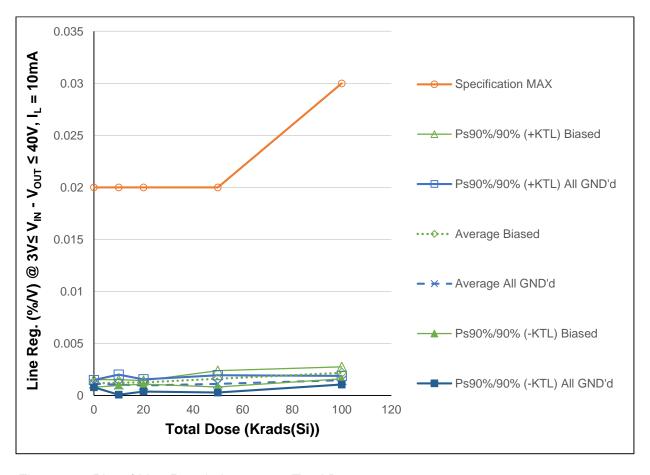


Figure 5.2: Plot of Line Regulation versus Total Dose



Table 5.2: Raw data for line regulation versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL under the second orange header)

	specification, and the status of th					
Paramete	r Line Reg @ 3V≤V <sub>I</sub> -V <sub>O</sub> ≤40V,I <sub>L</sub> =10mA			( ,,	<sup>®</sup> 50rads/se	
Units	(%/v)	0	10	20	50	100
72		0.001073	0.000863			
72		0.001181	0.001553			
72	<u> </u>	0.001094	0.000912			
72		0.001338	0.001233			
72		0.001012	0.000658			
73		0.001054	0.001327			
73		0.001219	0.001287			
73		0.001011	0.001073			
73		0.001325	0.001307			
73		0.001236	0.001243			
73		0.000969		0.000867		
73		0.000932		0.000830		
73		0.001072		0.000868		
73		0.001226		0.001347		
73		0.001136		0.000950		
74		0.001095		0.001205		
74		0.001016		0.001330		
74		0.001160		0.001199		
74	<u> </u>	0.000675		0.001291		
74		0.000912		0.001307		
74		0.001265			0.000998	
74		0.000809			0.000703	
74	<u> </u>	0.001097			0.001099	
74	<u> </u>	0.000972			0.001494	
74		0.001072			0.001326	
75		0.001317			0.001760	
75		0.000949			0.001327	
75		0.001141			0.001980	
75		0.001092			0.001654	
75		0.001097			0.001324	
75		0.000994				0.001550
75		0.001011				0.001667
75		0.001070				0.001496
75		0.000969				0.001287
75		0.000914				0.001357
76		0.000934				0.002337
76		0.000972				0.002132
76		0.001173				0.001997
76		0.001095				0.002466
76		0.001035				0.001995
72		0.001150	0.000763	0.000763	0.000763	0.000763
72		0.000967	0.001320	0.001320	0.001320	0.001320
	All GND'd Irradiation Statistics					
	Average All GND'd	0.001140	0.001044	0.000972	0.001124	0.001471
	Std Dev All GND'd	0.000126	0.000351	0.000214	0.000305	0.000152
	Ps90%/90% (+KTL) All GND'd	0.001485	0.002007	0.001560	0.001959	0.001888
	Ps90%/90% (-KTL) All GND'd	0.000794	0.000080	0.000385	0.000288	0.001054
	Biased Irradiation Statistics					
	Average Biased	0.001169	0.001247	0.001266	0.001609	0.002185
	Std Dev Biased	0.000132	0.000102	0.000061	0.000284	0.000210
	Ps90%/90% (+KTL) Biased	0.001530	0.001527	0.001432	0.002389	0.002761
	Ps90%/90% (-KTL) Biased	0.000807	0.000968	0.001100	0.000830	0.001610
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Specification MAX	0.02	0.02	0.02	0.02	0.03
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS



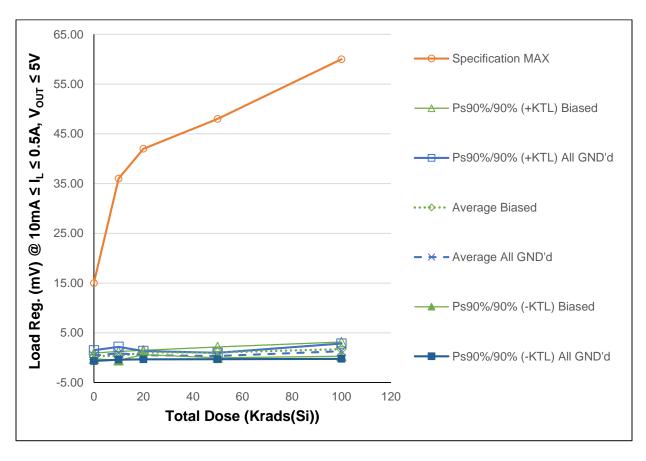


Figure 5.3: Plot of Load Regulation (V<sub>OUT</sub> ≤ 5V) versus Total Dose



Table 5.3: Raw data for load regulation ( $V_{OUT} \le 5V$ ) versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL).

	s, maximum specification, and the		or the test (	PASS/FAI	L).	
Parameter	Load Reg @ 10mA≤I <sub>L</sub> ≤0.5A,V <sub>O</sub> ≤5V		<mark>Γotal Dose (</mark> Ι	Krads(Si)) @	<sup>®</sup> 50rads/se	C
Units	(mV)	0	10	20	50	100
725		0.25177	0.54264			
726		0.03433	1.25980			
727		0.18597	1.07670			
728		1.03188	1.35326			
729		0.53120	0.27847			
730		0.41294	0.06580			
731		0.14877	0.01049			
732		0.67329	0.82016			
733	Biased Irradiation	0.30804	0.35381			
734		0.18406	0.48733			
735	All GND'd Irradiation	0.76866		0.75340		
736		0.15926		0.23746		
737	All GND'd Irradiation	0.73051		0.92316		
738		0.07820		0.36144		
739	All GND'd Irradiation	0.69237		0.29564		
740	Biased Irradiation	0.61893		1.13487		
741	Biased Irradiation	0.04387		1.07575		
742	Biased Irradiation	0.54932		0.84877		
743	Biased Irradiation	1.03283		1.25790		
744		0.58746		0.92506		
745	All GND'd Irradiation	0.43583			0.02098	
746	All GND'd Irradiation	0.56839			0.55313	
747	All GND'd Irradiation	0.42629			0.56171	
748	All GND'd Irradiation	0.08965			0.31376	
749	All GND'd Irradiation	0.51212			0.19932	
750	Biased Irradiation	0.60368			0.82874	
751		1.05476			1.13392	
752		0.90218			1.64890	
753		0.86498			1.07575	
754		0.64468			0.58079	
755		0.80395				1.27697
756		0.53024				1.03951
757		0.05341				0.86689
758		0.34046				1.09577
759		0.29278				2.27928
760		0.18311				1.53446
761		0.22507				1.70612
762		0.01526				2.54536
763		0.02480				1.10626
764		0.38815				1.76334
723		0.49019	0.12302	0.12302	0.12302	0.12302
724		0.96989	1.26839	1.26839	1.26839	1.26839
	All GND'd Irradiation Statistics	0.00000	1.20000	1.20000	1.20000	1.2000
	Average All GND'd	0.40703	0.90218	0.51422	0.32978	1.31168
	Std Dev All GND'd	0.39298	0.46907	0.30502	0.23255	0.56036
	Ps90%/90% (+KTL) All GND'd	1.48458	2.18837	1.35059	0.96743	2.84818
	Ps90%/90% (+KTL) All GND'd	-0.67052	-0.38401	-0.32214	-0.30786	-0.22481
	Biased Irradiation Statistics	0.07032	0.00401	0.02214	0.00700	0.22401
	Average Biased	0.34542	0.34752	1.04847	1.05362	1.73111
	Std Dev Biased	0.21105	0.33012	0.16369	0.39857	0.52292
	Ps90%/90% (+KTL) Biased	0.21105	1.25272	1.49731	2.14650	3.16495
	Ps90%/90% (+KTL) Biased Ps90%/90% (-KTL) Biased	-0.23327		0.59963		0.29727
	Specification MIN	-0.23327	-0.55768	0.53363	-0.03927	0.23121
	Status (Measurements) All GND'd					
	Status (Measurements) Biased	4.5	26	40	48	60
	Specification MAX	15	36	42		60
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Or a CASTLA AN STREET					
	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) Biased			_	_	
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS



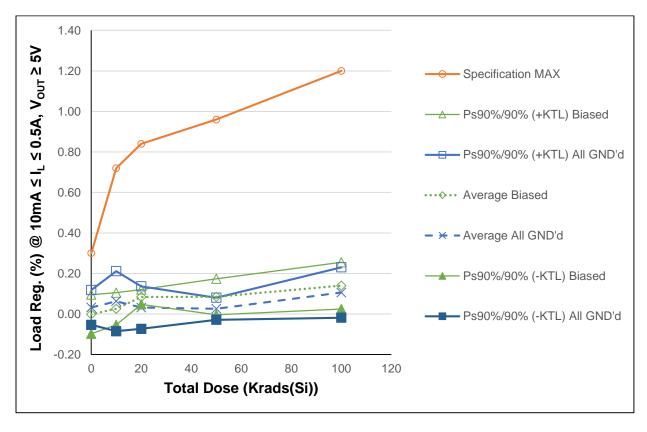


Figure 5.4: Plot of Load Regulation (V<sub>OUT</sub> ≥ 5V) versus Total Dose



Table 5.4: Raw data for load regulation ( $V_{OUT} \ge 5V$ ) versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL).

	s, maximum specification, and th	e status o	the test (	PASS/FAII	L).	
Parameter	Load Reg @ 10mA≤l <sub>L</sub> ≤0.5A,V <sub>O</sub> ≥5V		Total Dose (	Krads(Si)) @	2 50rads/se	c
Units	(%)	0	10	20	50	100
725		0.02013	0.04338			
726		0.00275	0.10109			
727		0.01493	0.08645			
728		0.08241	0.10808			
729		0.04251	-0.02229			
730		-0.03319	-0.00529			
73		0.01197	0.00084			
732		0.05401	0.06584			
733		-0.02474	0.02845			
734		-0.01477	0.03913			
735		0.06167		0.06048		
736		0.01278		0.01907		
737		0.05856		0.07406		
738		-0.00630		0.02913		
739	All GND'd Irradiation	0.05560		-0.02375		
740	Biased Irradiation	0.04973		0.09132		
741		0.00353		0.08673		
742		0.04408		0.06820		
743		0.08323		0.10151		
744		0.04716		0.07437		
745		0.03502			-0.00169	
746		0.04565			0.04453	
747	All GND'd Irradiation	0.03424			0.04520	
748		-0.00721			0.02531	
749		0.04115			0.01605	
750		0.04828			0.06662	
75°	Biased Irradiation	0.08462			0.09128	
752	Biased Irradiation	0.07261			0.13340	
753	Biased Irradiation	0.06930			0.08645	
754	Biased Irradiation	0.05170			0.04672	
755	All GND'd Irradiation	0.06478				0.10366
756	All GND'd Irradiation	0.04255				0.08399
757	All GND'd Irradiation	0.00428				0.07000
758	All GND'd Irradiation	0.02730				0.08841
759	All GND'd Irradiation	0.02354				0.18436
760	Biased Irradiation	-0.01472				0.12448
76	Biased Irradiation	0.01811				0.13827
762	Biased Irradiation	0.00122				0.20525
763	Biased Irradiation	0.00199				0.08957
764	Biased Irradiation	0.03112				0.14241
723	Control Unit	0.03913	0.00982	0.00982	0.00982	0.00982
724	Control Unit	0.07764	0.10149	0.10149	0.10149	0.10149
	All GND'd Irradiation Statistics					
	Average All GND'd	0.03255	0.06334	0.03180	0.02588	0.10608
	Std Dev All GND'd	0.03138	0.05406	0.03829	0.01986	0.04538
	Ps90%/90% (+KTL) All GND'd	0.11858	0.21159	0.13679	0.08034	0.23051
	Ps90%/90% (-KTL) All GND'd	-0.05349	-0.08490	-0.07319	-0.02859	-0.01834
	Biased Irradiation Statistics					
	Average Biased	-0.00134	0.02579	0.08443	0.08489	0.13999
	Std Dev Biased	0.03530	0.02906	0.01331	0.03235	0.04198
	Ps90%/90% (+KTL) Biased	0.09544	0.10547	0.12093	0.17360	0.25511
	Ps90%/90% (-KTL) Biased	-0.09813	-0.05388	0.04792	-0.00382	0.02488
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Specification MAX	0.3	0.72	0.84	0.96	1.2
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
_	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	3.12				1.00	
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS



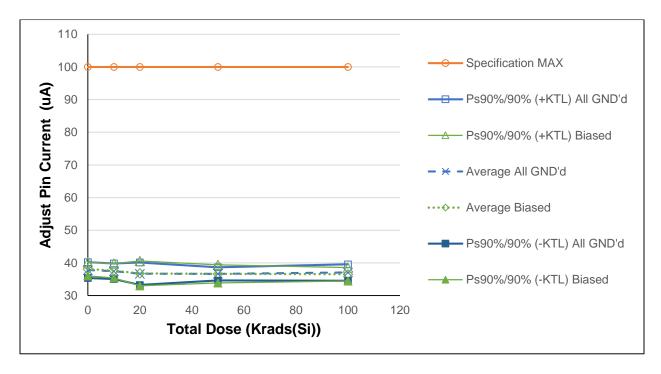


Figure 5.5: Plot of Adjust Pin Current versus Total Dose



*Table 5.5*: Raw data for adjust pin current versus total dose including the statistical calculations, minimum specification, maximum specification, and the status of the test (PASS/FAIL)

	Decincation, maximum specifica					
Parameter Units	Adjust Pin Current	0	10tal Dose (	Krads(Si)) @	50rads/se	100
725	(uA) All GND'd Irradiation	37.54211	37.32619	20	50	100
726		37.00259	36.45322			
727		39.32508	38.83184			
728		37.76212	37.60225			
729		37.46139	37.12873			
730		38.99350	38.60344			
731		38.69159	38.27301			
732		37.32824	36.63638			
733	Biased Irradiation	37.40420	37.16922			
734	Biased Irradiation	38.10794	37.47862			
735	All GND'd Irradiation	37.79535		35.92653		
736		36.73865		35.31767		
737		37.34129		36.17737		
738		38.55131		38.05889		
739		38.84967		37.99459		
740		37.26274		35.74931		
741		37.43744		36.32005		
742		39.12191		37.96959		
743 744		39.51522		38.57844 35.44489		
744		37.82265 38.20052		33.44469	37.52606	
745 746		36.89555			36.06564	
747		37.52430			35.87294	
748		37.19983			36.51036	
749		38.87934			37.32143	
750		38.98282			37.98863	
751		36.94541			36.26786	
752	Biased Irradiation	38.33011			36.92891	
753	Biased Irradiation	37.82858			36.85289	
754	Biased Irradiation	36.55329			35.22838	
755	All GND'd Irradiation	38.84136				37.75685
756		36.96201				36.22500
757		39.16700				38.32520
758		37.11417				36.39626
759		37.44833				36.70067
760		38.42290				37.41194
761		36.64942				35.56852
762 763		36.90386 38.04623				36.00272 37.01700
763		37.47683				36.68640
704		38.21854	37.96382	37.96382	37.96382	37.96382
724		37.95937	37.58915	37.58915	37.58915	37.58915
,	All GND'd Irradiation Statistics	07.55507	07.00010	07.00010	07.00010	07.00010
	Average All GND'd	37.81866	37.46845	36.69501	36.65929	37.08080
	Std Dev All GND'd	0.88637	0.87222	1.25545	0.73869	0.91530
	Ps90%/90% (+KTL) All GND'd	40.24908	39.86007	40.13746	38.68478	39.59054
	Ps90%/90% (-KTL) All GND'd	35.38824	35.07682	33.25256	34.63379	34.57106
	Biased Irradiation Statistics					
	Average Biased	38.10509	37.63213	36.81246	36.65333	36.53732
	Std Dev Biased	0.74633	0.80367	1.38750	1.00969	0.74861
	Ps90%/90% (+KTL) Biased	40.15152	39.83580	40.61698	39.42189	38.59000
	Ps90%/90% (-KTL) Biased	36.05867	35.42847	33.00793	33.88477	34.48464
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased	4.5.5	4.5.5	4.5.5	4.5.5	
	Specification MAX	100	100	100	100	100
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Status ( ICTL ) All CNIDIS					
	Status (-KTL) All GND'd Status (+KTL) All GND'd	DACC	DACC	DACC	DACC	PASS
	Status (+KTL) All GND 0	PASS	PASS	PASS	PASS	FASS
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS
	Otatus (+ICTL) Diaseu	1 700	1 700	1 700	1 733	1 700



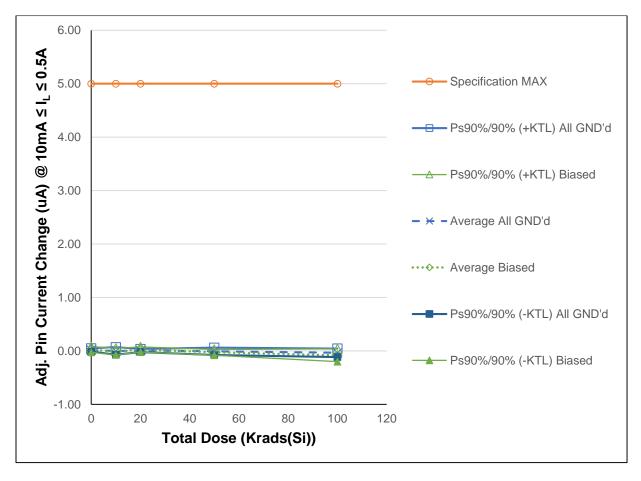


Figure 5.6: Plot of Adjust Pin Current Change @  $10mA \le I_{L} \le 0.5A$  versus Total Dose



*Table 5.6*: Raw data for adjust pin current change @ 10mA ≤  $I_L$  ≤ 0.5A versus total dose including the statistical calculations, minimum specification, and the status of the test (PASS/FAIL)

	al calculations, minimum specifi		a the statu	s of the tes	St (PASS/F	·AIL)
Parameter	Adjust I change @ 10mA≤ I <sub>L</sub> ≤0.5A	٦	Fotal Dose (I	Krads(Si)) @	<sup>®</sup> 50rads/see	0
Units	(uA)	0	10	20	50	100
725	All GND'd Irradiation	0.01186	-0.01190			
726	All GND'd Irradiation	0.01899	0.00239			
727	All GND'd Irradiation	0.00355	0.00477			
728		0.03324	-0.03095			
729	All GND'd Irradiation	0.02491	0.03810			
730	Biased Irradiation	0.00474	-0.00595			
731	Biased Irradiation	0.04153	-0.04287			
732	Biased Irradiation	0.01662	0.01905			
733	Biased Irradiation	0.05245	-0.01190			
734	Biased Irradiation	0.01780	-0.01647			
735	All GND'd Irradiation	0.00000		0.00000		
736	All GND'd Irradiation	0.01899		0.00000		
737	All GND'd Irradiation	-0.00357		0.02261		
738	All GND'd Irradiation	0.02730		0.00237		
739	All GND'd Irradiation	0.02018		0.01786		
740	Biased Irradiation	0.00831		0.03810		
741	Biased Irradiation	0.01070		0.03215		
742	Biased Irradiation	0.02515		0.04029		
743	Biased Irradiation	-0.02017		0.02857		
744	Biased Irradiation	0.00000		-0.00239		
745	All GND'd Irradiation	0.01781			-0.03197	
746	All GND'd Irradiation	0.01068			-0.01429	
747	All GND'd Irradiation	0.00950			0.00714	
748	All GND'd Irradiation	0.03442			-0.02619	
749	All GND'd Irradiation	0.01899			0.02859	
750	Biased Irradiation	0.03561			-0.01190	
751	Biased Irradiation	0.04770			-0.05119	
752	Biased Irradiation	0.01899			-0.00239	
753	Biased Irradiation	0.00949			-0.02500	
754	Biased Irradiation	0.03798			-0.03810	
755	All GND'd Irradiation	-0.00119				-0.03810
756		-0.00927				-0.01190
757		0.03680				-0.03692
758		0.02515				-0.07858
759		-0.00237				-0.00477
760		0.02849				-0.09527
761		-0.00118				-0.03810
762		0.04155				-0.02858
763		0.01543				-0.11787
764		0.04392				-0.12125
723		0.03820	0.02720	0.02720	0.02720	0.02720
724		0.01781	-0.02858	-0.02858	-0.02858	-0.02858
	All GND'd Irradiation Statistics					
	Average All GND'd	0.01851	0.00048	0.00857	-0.00734	-0.03405
	Std Dev All GND'd	0.01147	0.02539	0.01083	0.02506	0.02896
	Ps90%/90% (+KTL) All GND'd	0.04996	0.07010	0.03825	0.06136	0.04536
	Ps90%/90% (-KTL) All GND'd	-0.01294	-0.06914	-0.02111	-0.07605	-0.11347
	Biased Irradiation Statistics					
	Average Biased	0.02663	-0.01163	0.02734	-0.02572	-0.08021
	Std Dev Biased	0.01966	0.02221	0.01726	0.01961	0.04407
	Ps90%/90% (+KTL) Biased	0.08053	0.04927	0.07467	0.02805	0.04062
	Ps90%/90% (-KTL) Biased	-0.02727	-0.07253	-0.01999	-0.07948	-0.20105
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Specification MAX	5	5	5	5	5
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Time (made of the file) Bladda	00	00	00	00	
	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Cado (TITE) / III OIND U	. ,	. , ,,,,,,	. , .00	. , .00	. 7.00
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS
	Totatas (+ICIE) Diaseu	1 700	1 700	1 700	1 700	1 700



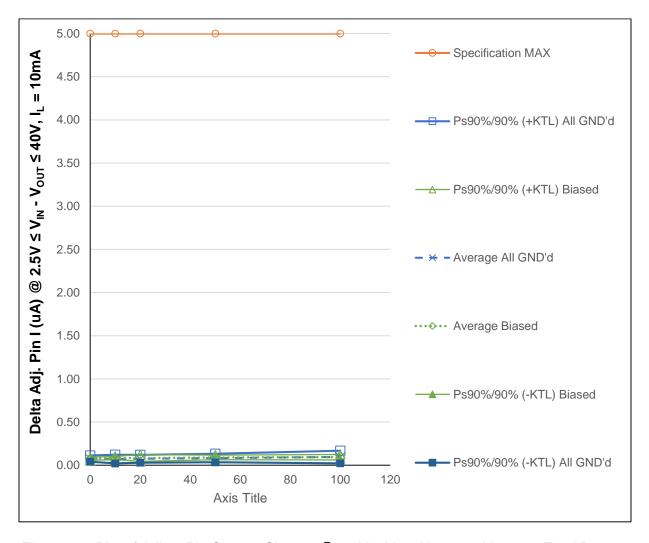


Figure 5.7: Plot of Adjust Pin Current Change @  $2.5V \le V_{IN} - V_{OUT} \le 40V$  versus Total Dose



*Table 5.7*: Raw data table for adjust pin current change @  $2.5V \le V_{IN} - V_{OUT} \le 40V$  versus total dose including the statistical calculations, maximum specification, and the status of the test.

	ig the statistical calculations, in	liaxilliulli s	sp <del>e</del> cilication	ni, and the	sialus oi i	iie iesi.
Parameter	Delta Adj. I @ 2.5V≤V <sub>IN</sub> -V <sub>OUT</sub> ≤ 40V	-	Total Dose (	Krads(Si))	@ 50rads/sed	
Units	(uA)	0	10	20	50	100
725	All GND'd Irradiation	0.08212	0.06671			
726	All GND'd Irradiation	0.09732	0.06906			
727	All GND'd Irradiation	0.07122	0.10221			
728	All GND'd Irradiation	0.07122	0.06887			
729	All GND'd Irradiation	0.06291	0.05240			
730	Biased Irradiation	0.06528	0.07619			
731	Biased Irradiation	0.08190	0.09029			
732	Biased Irradiation	0.07359	0.08931			
733	Biased Irradiation	0.07263	0.07602			
734	Biased Irradiation	0.07953	0.08554			
735	All GND'd Irradiation	0.05103		0.10102		
736	All GND'd Irradiation	0.08094		0.07602		
737	All GND'd Irradiation	0.06885		0.07619		
738	All GND'd Irradiation	0.08427		0.05696		
739	All GND'd Irradiation	0.06171		0.06550		
740						
	Biased Irradiation	0.07618		0.07619		
741	Biased Irradiation	0.07618		0.08573		
742	Biased Irradiation	0.06171		0.06311		
743	Biased Irradiation	0.06311		0.08929		
744	Biased Irradiation	0.06193		0.10102		
745	All GND'd Irradiation	0.05600			0.07619	
746	All GND'd Irradiation	0.04866			0.07600	
747	All GND'd Irradiation	0.08568			0.07858	
748	All GND'd Irradiation	0.08449			0.07145	
749					0.11551	
	All GND'd Irradiation	0.07855				
750	Biased Irradiation	0.07240			0.09406	
751	Biased Irradiation	0.06430			0.09029	
752	Biased Irradiation	0.07737			0.07619	
753	Biased Irradiation	0.08925			0.08554	
754	Biased Irradiation	0.06289			0.10239	
755	All GND'd Irradiation	0.06054				0.11768
756	All GND'd Irradiation	0.07263				0.06905
757	All GND'd Irradiation	0.07715				0.12602
758	All GND'd Irradiation	0.07499				0.09505
759	All GND'd Irradiation	0.09377				0.06887
760	Biased Irradiation	0.07953				0.10102
761	Biased Irradiation	0.06669				0.07858
762	Biased Irradiation	0.08784				0.08912
763	Biased Irradiation	0.07240				0.10816
764	Biased Irradiation	0.07596				0.09029
723	Control Unit	0.06647	0.04744	0.04744	0.04744	0.04744
724	Control Unit	0.07240	0.07600	0.07600	0.07600	0.07600
	All GND'd Irradiation Statistics	0.0.2.0	0.07.000	0.0.00	0.07.000	0.0.00
	Average All GND'd	0.07696	0.07185	0.07514	0.08355	0.09534
	Std Dev All GND'd			0.07514		
		0.01327	0.01832		0.01805	0.02661
	Ps90%/90% (+KTL) All GND'd	0.11335	0.12210	0.12051	0.13305	0.16830
	Ps90%/90% (-KTL) All GND'd	0.04056	0.02160	0.02976	0.03404	0.02237
	Biased Irradiation Statistics					
	Average Biased	0.07458	0.08347	0.08307	0.08970	0.09343
	Std Dev Biased	0.00651	0.00695	0.01426	0.00975	0.01144
	Ps90%/90% (+KTL) Biased	0.09242	0.10253	0.12217	0.11642	0.12481
	Ps90%/90% (-KTL) Biased	0.05675	0.06441	0.04396	0.06297	0.06206
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Specification MAX	5	5	5	5	5
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	·					
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS
	Otatus (+ICTL) Diaseu	1 700	1 700	1 400	1 700	1 700



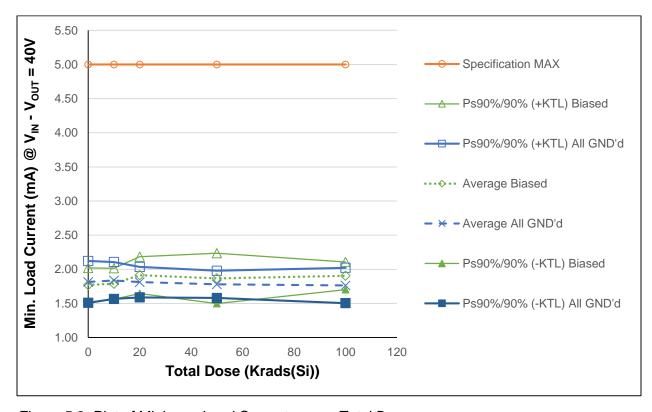


Figure 5.8: Plot of Minimum Load Current versus Total Dose



Table 5.8: Raw data table for minimum load current versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL)

aicuiations,	, maximum specification, and tr	ie status c	n the test (	PASS/FAI	L)	
Parameter	Min. Load I @ $V_{IN}$ - $V_{OUT} = 40V$	-	Total Dose (	Krads(Si)) @	<sup>20</sup> 50rads/sed	
Units	(mA)	0	10	20	50	100
725	All GND'd Irradiation	1.88504	1.89667			
726		1.62425	1.66741			
727		1.80678	1.83360			
728		1.86683	1.87531			
729	All GND'd Irradiation	1.89265	1.90827			
730	Biased Irradiation	1.87291	1.87562			
731	Biased Irradiation	1.86622	1.87898			
732	Biased Irradiation	1.69738	1.74474			
733	Biased Irradiation	1.70128	1.69853			
734	Biased Irradiation	1.71133	1.74635			
735	All GND'd Irradiation	1.68094		1.82193		
736		1.61137		1.72827		
737	All GND'd Irradiation	1.64193		1.73162		
738	All GND'd Irradiation	1.88983		1.91269		
739	All GND'd Irradiation	1.80001		1.86411		
740	Biased Irradiation	1.68908		1.80393		
740	Biased Irradiation	1.86339		1.93275		
741	Biased Irradiation	1.79307		1.87936		
743	Biased Irradiation	1.89333		2.06912		
743	Biased Irradiation	1.69799		1.88523		
745	All GND'd Irradiation	1.68155		1.00020	1.71301	
745	All GND'd Irradiation	1.67026			1.71911	
747	All GND'd Irradiation  All GND'd Irradiation	1.65038			1.76915	
748	All GND'd Irradiation	1.76466			1.80613	
749	All GND'd Irradiation	1.78576			1.89027	
750	Biased Irradiation	1.95482			2.03884	
751	Biased Irradiation	1.64954			1.76503	
751	Biased Irradiation	1.88198			1.98301	
753	Biased Irradiation	1.61595			1.74474	
754	Biased Irradiation Biased Irradiation	1.62173			1.80240	
755	All GND'd Irradiation				1.00240	1.89927
756	All GND'd Irradiation	1.86134 1.69976				1.72889
757	All GND'd Irradiation	1.79178				1.81492
758	All GND'd Irradiation	1.63400				1.66008
759	All GND'd Irradiation					1.71133
760	Biased Irradiation	1.68695 1.82104				1.97660
760	Biased Irradiation Biased Irradiation	1.70736				1.88538
762	Biased Irradiation	1.64123				1.83016
763	Biased Irradiation Biased Irradiation					
764	Biased Irradiation Biased Irradiation	1.81929				1.98881 1.84419
723		1.68390 1.91924	1.93587	1.93587	1.93587	1.93587
723					+	
124	Control Unit All GND'd Irradiation Statistics	1.61023	1.63797	1.63797	1.63797	1.63797
	Average All GND'd	1.81511	1.83625	1.81173	1.77953	1.76290
	Std Dev All GND'd		0.09859	0.08128	0.07272	
	Ps90%/90% (+KTL) All GND'd	0.11188	2.10658		1.97893	0.09446
		2.12189		2.03459		2.02190
	Ps90%/90% (-KTL) All GND'd	1.50832	1.56593	1.58887	1.58013	1.50389
	Biased Irradiation Statistics	1.76983	1 70004	1.91408	1.96694	1.90503
	Average Biased Std Dev Biased		1.78884		1.86681	
	Ps90%/90% (+KTL) Biased	0.09122	0.08301	0.09818	0.13463	0.07388
		2.01996	2.01645	2.18329	2.23597	2.10761
	Ps90%/90% (-KTL) Biased	1.51969	1.56124	1.64487	1.49764	1.70245
	Specification MIN					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased	_	_	_	_	
	Specification MAX	5	5	5	5	5
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	O (1671) All 5: 5:					
	Status (-KTL) All GND'd					
	Status (+KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) Biased					
	Status (+KTL) Biased	PASS	PASS	PASS	PASS	PASS



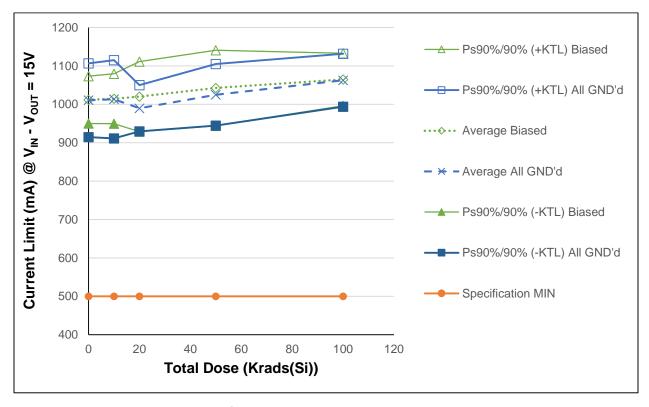


Figure 5.9: Plot of Current Limit @  $V_{IN} - V_{OUT} = 15V$  versus Total Dose



*Table 5.9*: Raw data table for current limit @  $V_{IN} - V_{OUT} \le 15V$  versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL)

	calculations, maximum specific	alion, and	ine status	or the test	(PASS/FF	<b>\</b> 1∟ <i>)</i>
Parameter	Current Limit @ $V_{IN} - V_{OUT} = 15V$	٦	<mark>Fotal Dose (I</mark>	Krads(Si)) @	<u>50rads/sec</u>	0
Units	(mA)	0	10	20	50	100
725	All GND'd Irradiation	1032.746	1038.372			
726	All GND'd Irradiation	948.552	947.694			
727	All GND'd Irradiation	1021.290	1022.457			
728	All GND'd Irradiation	1028.333	1031.551			
729	All GND'd Irradiation	1022.648	1025.849			
730	Biased Irradiation	1040.608	1044.949			
731	Biased Irradiation	1026.064	1028.665			
732	Biased Irradiation	981.997	982.223			
733	Biased Irradiation	1002.295	1008.319			
734	Biased Irradiation	1007.698	1008.492			
735	All GND'd Irradiation	972.018		976.446		
736	All GND'd Irradiation	951.417		959.095		
737	All GND'd Irradiation	987.605		995.637		
738	All GND'd Irradiation	997.859		1013.923		
739	All GND'd Irradiation	990.225		1003.455		
740	Biased Irradiation	981.781		986.572		
741	Biased Irradiation	1055.027		1068.020		
742	Biased Irradiation	996.953		1005.198		
743	Biased Irradiation	1029.640		1040.093		
744	Biased Irradiation	999.425		1000.243		
745	All GND'd Irradiation	969.599			1003.064	
746	All GND'd Irradiation	1004.508			1044.422	
747	All GND'd Irradiation	957.892			984.410	
748	All GND'd Irradiation	1008.179			1049.651	
749	All GND'd Irradiation	1013.876			1042.725	
750	Biased Irradiation	1042.961			1081.679	
751	Biased Irradiation	993.075			1037.825	
752	Biased Irradiation	1045.514			1077.500	
753	Biased Irradiation	975.324			1007.422	
754	Biased Irradiation	972.372			1008.740	
755	All GND'd Irradiation	1028.600				1088.880
756	All GND'd Irradiation	1015.542				1078.640
757	All GND'd Irradiation	1007.484				1074.110
758	All GND'd Irradiation	975.464				1036.547
759	All GND'd Irradiation	975.078				1034.802
760	Biased Irradiation	1024.091				1088.154
761	Biased Irradiation	993.250				1051.839
762	Biased Irradiation	967.981				1027.136
763	Biased Irradiation	1011.465				1079.129
764	Biased Irradiation	1009.018				1077.132
723	Control Unit	1064.786	1051.057	1051.057	1051.057	1051.057
724	Control Unit	989.091	975.181	975.181	975.181	975.181
	All GND'd Irradiation Statistics					
	Average All GND'd	1010.714	1013.185	989.711	1024.854	1062.596
	Std Dev All GND'd	35.051	37.105	21.929	29.273	25.159
	Ps90%/90% (+KTL) All GND'd	1106.823	1114.926	1049.841	1105.121	1131.582
	Ps90%/90% (-KTL) All GND'd	914.605	911.443	929.581	944.587	993.610
	Biased Irradiation Statistics					
	Average Biased	1011.732	1014.530	1020.025	1042.633	1064.678
	Std Dev Biased	22.521	23.685	33.304	35.889	24.946
	Ps90%/90% (+KTL) Biased	1073.484	1079.473	1111.344	1141.040	1133.081
	Ps90%/90% (-KTL) Biased	949.980	949.586	928.707	944.227	996.275
	Specification MIN	500	500	500	500	500
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Specification MAX					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Catas (Moderationion) Diaged					
	Status (-KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (+KTL) All GND'd	1 7.00	1 7.00	1 7.00	17.00	1 / 100
	Ciaias (FICIL) All GIVD a					
	Status (-KTL) Biased	PASS	PASS	PASS	PASS	PASS
	Status (-KTL) Biased Status (+KTL) Biased	1 700	1 700	1 700	1 700	1 700
	Oldido (TIVIL) Diaseu					



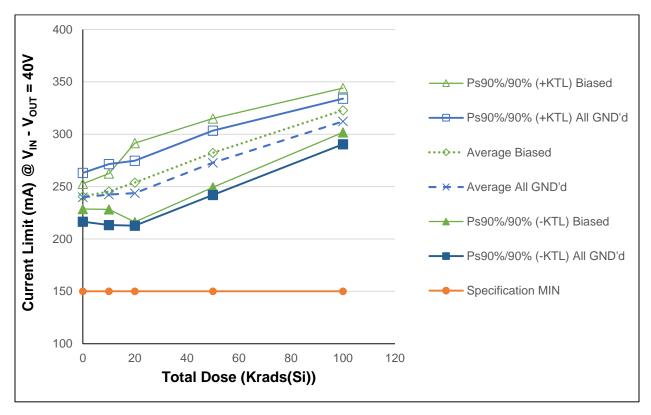


Figure 5.10: Plot of Current Limit @  $V_{IN} - V_{OUT} = 40V$  versus Total Dose



*Table 5.10*: Raw data table for current limit @  $V_{IN} - V_{OUT} = 40V$  versus total dose including the statistical calculations, maximum specification, and the status of the test (PASS/FAIL)

	alculations, maximum specificat					
Parameter	114 001	0		Krads(Si)) @		
Units 725	(mA) All GND'd Irradiation	244.211	10 249.428	20	50	100
726		226.769	225.737			
727		243.588	244.228			
728		248.295	253.037			
729		236.349	239.784			
730		243.693	249.807			
731		239.376	244.926			
732		233.639	235.803			
733		244.481	251.913			
734		242.097	244.315			
735		230.695	2111010	236.461		
736		224.149		232.180		
737		231.385		238.435		
738		240.915		257.356		
739		240.844		254.305		
740		232.644		240.885		
741	Biased Irradiation	245.120		260.867		
742		242.111		253.644		
743		258.790		273.002		
744		236.042		240.809		
745		228.208			263.131	
746		236.297			277.408	
747		233.389			262.579	
748		246.476			289.559	
749		240.539			271.038	
750		245.419			292.014	
751		241.771			292.745	
752		245.154			286.581	
753		227.185			265.193	
754		231.795			274.578	
755		246.065				314.756
756		246.817				318.051
757		245.332				319.230
758		241.551				309.662
759		233.663				299.703
760		249.992				330.417
761	Biased Irradiation	241.362				314.694
762		242.099				315.011
763		242.294				324.684
764		246.545				329.797
723	•	248.412	235.398	235.398	235.398	235.398
724		226.792	212.647	212.647	212.647	212.647
	All GND'd Irradiation Statistics					
	Average All GND'd	239.843	242.443	243.747	272.743	312.281
	Std Dev All GND'd	8.480	10.611	11.311	11.215	7.949
	Ps90%/90% (+KTL) All GND'd	263.096	271.538	274.763	303.496	334.077
	Ps90%/90% (-KTL) All GND'd	216.589	213.348	212.732	241.990	290.484
	Biased Irradiation Statistics					
	Average Biased	240.657	245.353	253.842	282.222	322.921
	Std Dev Biased	4.382	6.232	13.732	11.979	7.694
	Ps90%/90% (+KTL) Biased	252.672	262.440	291.494	315.070	344.019
	Ps90%/90% (-KTL) Biased	228.643	228.266	216.189	249.374	301.822
	Specification MIN	150	150	150	150	150
	Status (Measurements) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (Measurements) Biased	PASS	PASS	PASS	PASS	PASS
	Specification MAX					
	Status (Measurements) All GND'd					
	Status (Measurements) Biased					
	Status (-KTL) All GND'd	PASS	PASS	PASS	PASS	PASS
	Status (+KTL) All GND'd					
	Status (+KTL) All GND'd					
	Status (+KTL) All GND'd Status (-KTL) Biased	PASS	PASS	PASS	PASS	PASS



## Appendix A



Figure A1: Top View showing ID and Date Code



Figure A2: Side View showing serial number



## Appendix B

## **Radiation Bias Connection Tables**

Table B1: Biased Conditions

PIN	FUNCTION	CONNECTION / BIAS
1	INPUT	+15V,to -15V via 0.1µF
2	ADJUST	To -15V via 2KΩ
3	OUTPUT	To -15V via 61.9Ω

## Table B2: All GND'd

PIN	FUNCTION	CONNECTION / BIAS
1	INPUT	Ground
2	ADJUST	Ground
3	OUTPUT	Ground



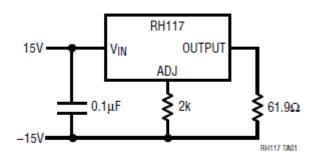


Figure B1: Total Dose Bias Circuit

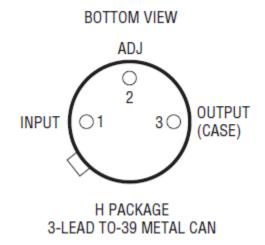


Figure B2: Pin-Out





Figure B3: Bias Board (top view)



Figure B4: Bias Board (bottom view)



## Appendix C

#### TEST CERTIFICATE



Defense Microelectronics Activity Science and Engineering Gamma Irradiation Test Facility DMEA/MEBC 4234 54th Street McClellan, CA 95652



Testing Certificate Number: 1691.01

This laboratory is accredited by the American Association for Laboratory Accreditation (A2LA) and the dosimetry reported in this test certificate has been determined in accordance with the laboratory's terms of accreditation. The results contained herein relate only to the items tested. This certificate may not be reproduced, except in full, without the approval of this laboratory.

2014-09-24 Test Certificate #: 2014-NRC-031 Total Pages (except cover): 2

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RI	EQUEST FOR AND	RESULT	S OF TES	STS	PAGE N	O. NO. OF PAGE 2
	SE	ECTION A - RE	QUEST FOR	TEST	1	2
. TO: (Include ZIP Code) Defense Microelectronics Activi icience and Engineering Gamms 1234 54th Street McClellan, CA 95652-2100	•		2. FROM: (Incl Dr. Sana Rezg Linear Techno 1630 McCarth Milpitas, CA	pui ology Corp. ny Blvd. 95035		
viccienan, CA 93032-2100			Phone: (408) 4 Email: srezgu			
3. PRIME CONTRACTOR AND A Same as block 2	DDRESS (Include ZIP Code)	4. MANUFACT Linear Techno 1630 McCarth Milpitas, CA 9	ıy Blvd.	O ADDRESS (Include	e ZIP Code)	
CONTRACT NUMBER CRADA			P.O. NUMBE			
5. END ITEM AND/OR PROJECT N/		6. SAMPLE NUMBER N/A	7. LOT NO. See below	8. REASON FOR SUBMIT Total Ionizing Dose		9. DATE SUBMITTED 2014-09-23
IO. MATERIAL TO BE TESTED arious biased/unbiased devices - see ellow	10a. QUANTITY SUBMITTED  See below	11. QUANTITY REPRESEN		12. SPEC. & AMEND AND SAMPLE & DATE	D/OR DRAWING NO	. & REV. FOR
13. PURCHASED FROM OR SOU Linear Techn		14. SHIPMEN		15. DATE SAMPLED AND 2014-09	O SUBMITTED BY 9-23 by Tom Sheph	erd
Description of parts to be irradiated is as for RH117H, fab lot #W10905063.1, assly lot WQRH117MK-CS, fab lot #W0944174.1 WORH117MK-CS, fab lot #W0944174.1	flows: #755614.1, WFR #10: 10, 20, 50 and 100 ass'y lot #764506.2, WFR #4: 50 and 100 ass'y lot #764507.2, WFR #11: 50 and 10	krad(SiO2), 10 device krad(SiO2), 5 devices 0 krad(SiO2), 5 devices	es per dose level, bias s per dose level, biase es per dose level, bias	rd sed	rs, devices, etc. to suit test	requirements.
Description of parts to be imadiated is as for RH117H, fab lot #W10905063.1, assly lot WVQRH117MK.CS, fab lot #W0944174.1 WQRH117MK.CS, fab lot #W0944174.1 WQRH117MK.CS, fab lot #W0944174.1 WQRH117MK.CS, fab lot #W0944174.1 WQRH13MK.CS, fab lot #W0944174.1 WQRH3083MK.CS, fab lot #HP210682.1 WQRH3083MK.CS, fab lot #HP210682.1 Experiment #. 2014-NRC-031	Blows: #755614.1, WFR #10: 10, 20, 50 and 100 #755614.1, WFR #10: 10, 20, 50 and 100 ass'y lot #764506.2, WFR #4: 50 and 100 ass'y lot #764507.2, WFR #21: 50 and 10 ass'y lot #764509.2, WFR #20: 50 and 10 l, ass'y lot #784501.2, WFR #2: 50 and 200 l, ass'y lot #784601.2, WFR #2: 50 and 200 DMEA Approval: SHEPPS	krad(SiO2), 10 device krad(SiO2), 5 device 0 krad(SiO2), 5 device	es per dose level, bias s per dose level, bias es per dose level, bias es per dose level, bias es per dose level, bias s per dose level, bias s per dose level, bias s per dose level, bias	ed d ded eed eed eed eed eed eed eed ee	CAL SHARES ME	INE CARY
escription of parts to be irradiated is as for RRH17H, fab los #W10905063.1, asoly 10WRH17MCCS, fab los #W0944174.1 WQRH117MCCS, fab los #W0944174.1 WQRH17MCCS, fab los #W0944174.1 WQRH17MCS, fab los #W0944174.1 WQRH17MCS, fab los #HP210682.1 WQRH3083MC-CS, fab los #HP210682.2 Experiment #. 2014-NRC-031 7. SEND REPORT OF TEST TO ddividual identified in Block 2	Blows: #755614.1, WFR #10: 10, 20, 50 and 100 #755614.1, WFR #10: 10, 20, 50 and 100 ass'y lot #764506.2, WFR #4: 50 and 100 ass'y lot #764507.2, WFR #21: 50 and 10 ass'y lot #764509.2, WFR #20: 50 and 10 l, ass'y lot #784501.2, WFR #2: 50 and 200 l, ass'y lot #784601.2, WFR #2: 50 and 200 DMEA Approval: SHEPPS	krad(SiO2), 10 devices krad(SiO2), 5 devices 0 krad(SiO2), 5 devices ERD.THCM.	es per dose level, biase s per dose level, biase es per dose level, biase se per dose level, bias se per dose level, bias	ied of sed	OM Section Comments of the Com	INE CARY
Description of parts to be irradiated is as for RH117H, fab lot #W10905063.1, assly lot WQRH117MK.CS, fab lot #W0944174.1 WQRH117MK.CS, fab lot #W0944174.1 WQRH117MK.CS, fab lot #W0944174.1 WQRH107MK.CS, fab lot #W0944174.1 WQRH107MK.CS, fab lot #HP210682.1 WQRH3083MK.CS, fab lot #HP210682.1 Experiment #. 2014-NRC-031  17. SEND REPORT OF TEST TO individual identified in Block 2  § 1. DATE SAMPLE RECEIVED	Blows: #755614.1, WFR #10: 10, 20, 50 and 100, ass'y lot #764506.2, WFR #4: 50 and 100, ass'y lot #764507.2, WFR #11: 50 and 10, ass'y lot #764507.2, WFR #20: 50 and 10, ass'y lot #764509.2, WFR #20: 50 and 10, ass'y lot #764509.2, WFR #2: 50 and 10, ass'y lot #783601.2, WFR #2: 50 and 200, ass'y lot #783602.2, WFR #3: 50 and 200, ass'y lot #783602.2, with #3: 50 and 200, ass'y lot #783602.2, w	krad(SiO2), 10 device krad(SiO2), 5 device 0 krad(SiO2), 5 device ERD.THOM	es per dose level, biase s per dose level, biase se per dose level, biase se per dose level, bias se p	ed did ed	ow the second was the second with the second was the second w	INE CARY
Description of parts to be irradiated is as for RH117H, fab los #W10905063.1, assly lot WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #HP210682.1 WORH3083MK.CS, fab lot #HP210682.1 WORH3083MK.CS, fab lot #HP210682.1 Experiment #: 2014-NRC-031  17. SEND REPORT OF TEST TO Individual identified in Block 2	Blows: #755614.1, WFR #10: 10, 20, 50 and 100, ass'y lot #764506.2, WFR #4: 50 and 100, ass'y lot #764507.2, WFR #11: 50 and 10, ass'y lot #764507.2, WFR #20: 50 and 10, ass'y lot #764509.2, WFR #20: 50 and 10, ass'y lot #764509.2, WFR #2: 50 and 10, ass'y lot #783601.2, WFR #2: 50 and 200, ass'y lot #783602.2, WFR #3: 50 and 200, ass'y lot #783602.2, with #3: 50 and 200, ass'y lot #783602.2, w	krad(SiO2), 10 devices krad(SiO2), 5 devices 0 krad(Si	es per dose level, biase sper dose level, biase es per dose level, biase es per dose level, biase es per dose level, bias es per dose level, bias sper dose level, bias sper dose level, bias sper dose level, bias per dos	ed did ed	CM NAME OF THE OWN OF T	LINE. CARY, WESTER CONTROL OF THE PROPERTY OF
Description of parts to be irradiated is as for RH117H, fab loc #W10905063.1, assly lot WVQRH17MK.CS, fab loc #W0944174.1 WQRH17MK.CS, fab loc #W0944174.1 WQRH17MK.CS, fab loc #W0944174.1 WQRH17MK.CS, fab loc #W0944174.1 WQRH3083MK.CS, fab loc #W0944174.1 WQRH3083MK.CS, fab loc #HP210682.1 Experiment #: 2014-NRC-031  17. SEND REPORT OF TEST TO individual identified in Block 2  S. I. DATE SAMPLE RECEIVED  2014-09-24	Blows: #755614.1, WFR #10: 10, 20, 50 and 100 #755614.1, WFR #10: 10, 20, 50 and 100 ass'y lot #764506.2, WFR #4: 50 and 100 ass'y lot #764507.2, WFR #11: 50 and 10 ass'y lot #764509.2, WFR #25: 50 and 100 ass'y lot #764509.2, WFR #25: 50 and 200 ass'y lot #784601.2, WFR #2: 50 and 200 DMEA Approval:  DMEA Approval:  #85.112  SECTION B - RESULTS OF 1  2. DATE RES	krad(SiO2), 10 device krad(SiO2), 5 device 0	es per dose level, biase sper dose level, biase es per dose level, biase es per dose level, biase es per dose level, bias es per dose level, bias sper dose level, bias sper dose level, bias sper dose level, bias per dos	ed of led ed e	CM NAME OF THE OWN OF T	LINE CARY, MESSES and the same
Description of parts to be irradiated is as for RH117H, fab lot #W10905063.1, assly lot WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH117MK.CS, fab lot #W0944174.1 WORH17MK.CS, fab lot #W0944174.1 WORH3083MK.CS, fab lot #W19417682.1 WORH3083MK.CS, fab lot #HP210682.1 The Second Parts of the Part	Blows: #755614.1, WFR #10: 10, 20, 50 and 100 , ass'y lot #764506.2, WFR #4: 50 and 100 , ass'y lot #764507.2, WFR #11: 50 and 100 , ass'y lot #764507.2, WFR #11: 50 and 100 , ass'y lot #764508.2, WFR #20: 50 and 100 , ass'y lot #764509.2, WFR #2: 50 and 100 , ass'y lot #785601.2, WFR #2: 50 and 200 , ass'y lot #785602.2, WFR #3: 50 and 200  DMEA Approval:  BECTION B - RESULTS OF 1  2. DATE RES  RESULTS O	krad(SiO2), 10 devices krad(SiO2), 5 devices 0 krad(Si	es per dose level, biase s per dose level, biase es per dose level, bias es per dose level, bias es per dose level, bias s per dose level, bias s per dose level, bias s per dose level, bias per dose	ed ded ed	Sequired)  Continued by the sequence of the se	LINE_CARY SET TO THE METERS OF



Cor	tinuation of DD Form 1222				Experiment #:	2014-1	NRC-031	Page 2 of 2		
4.	Test Performed		Result	s of Test	_	Samp	le Result	Requirements		Step No.
_	20140924 09:20:00 to 20140924 09:23:08	1.000E+04	rad(SiO2) at	3.199E+03	rad(SiO2)/min	RH117H,	WFR #10	, S/Ns 0725-0744:	10 krad SD, 10 krad TD	1
	20140924 09:29:25 to 20140924 09:32:33	1.000E+04	rad(SiO2) at	3.199E+03	rad(SiO2)/min	RH117H,	WFR #10	, S/Ns 0735-0744:	10 krad SD, 20 krad TD	2
	20140924 09:50:05 to 20140924 10:05:43	5.000E+04	rad(SiO2) at	3.199E+03	rad(SiO2)/min	RH117H,	WFR #10	, S/Ns 0745-0764:	50 krad SD, 50 krad TD	3
	20140924 10:11:50 to 20140924 10:27:28	5.000E+04	rad(SiO2) at	3.199E+03	rad(SiO2)/min	RH117H,	WFR #10	, S/Ns 0755-0764:	50 krad SD, 100 krad TD	4
	20140924 10:43:30 to 20140924 10:59:52	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #4, S/Ns 1-2	, 4-6: 50 krad TD	5
	20140924 10:43:30 to 20140924 10:59:52	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #11, S/Ns 1-	5: 50 krad TD	5
	20140924 11:10:45 to 20140924 11:27:07	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #20, S/Ns 1-	5: 50 krad TD	6
	20140924 11:10:45 to 20140924 11:27:07	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #25, S/Ns 1-	5: 50 krad TD	6
	20140924 11:39:00 to 20140924 12:11:44	1.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #4, S/Ns 7-1	1: 100 krad TD	7
_	20140924 11:39:00 to 20140924 12:11:44	1.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #11, S/Ns 6-	8, 10-11: 100 krad TD	7
	20140924 12:22:40 to 20140924 12:55:24	1.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #20, S/Ns 6-	10: 100 krad TD	8
	20140924 12:22:40 to 20140924 12:55:24	1.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH11	7MK-CS,	WFR #25, S/Ns 6-	10: 100 krad TD	8
	20140924 13:26:45 to 20140924 13:43:07	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH30	83MK-CS	, WFR #2, S/Ns 1-	5: 50 krad TD	9
	20140924 13:26:45 to 20140924 13:43:07	5.000E+04	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH30	83MK-CS	, WFR #3, S/Ns 1-	5: 50 krad TD	9
	20140924 13:56:00 to 20140924 15:01:29	2.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH30	83MK-CS	, WFR #2, S/Ns 6-	10: 200 krad TD	10
	20140924 13:56:00 to 20140924 15:01:29	2.000E+05	rad(SiO2) at	3.054E+03	rad(SiO2)/min	WQRH30	83MK-CS	, WFR #3, S/Ns 6-	10: 200 krad TD	10

Uncertainty: Total Doses reported are ± 10.91% (RH117H)

15.86% (WQRH117MK-CS, WQRH3083MK-CS)

Reported uncertainties represent expanded uncertainties expressed at approximately the 95% confidence level using a coverage factor of k=2. 

#### NOTES:

- 1. ASTM = American Society for Testing and Materials.
- 2. DUT = Device Under Test.
- 3. S/N = Serial Number.
- 4. SD = Step Dose.
- 5. TD = Total Dose.
- 6. WFR = Wafer.
- 7. Dose rate uniformity across target area: ± 4.59% (RH117H)
  - 9.55% (WQRH117MK-CS, WQRH3083MK-CS)
- 8. All irradiation steps met the requirements of MIL-STD-883H, Test Method 1019.8, Condition A.
- 9. Source information:
- a. Irradiator = J.L. Shepherd & Associates Model 81-22/484 self-contained irradiation facility, S/Ns 7125/50016.
- b. Source selection = two large Co-60 sources.
- 10. Dosimeter system:
  - a. Radcal Model No. 9010 Radiation Monitor Controller, S/N 90-1313.
  - b. Radcal Model No. 90X5-0.18 Electrometer/Ion Chamber, S/Ns 95-0478/9771.
  - c. This dosimeter system was calibrated per ISO/IEC 17025:2005 by University of Wisconsin Medical Radiation Research Center on 3 Feb 2014 (Report No. ION14425). This calibration is effective for two years.
- 11. Irradiation geometry: in accordance with section 7.3.2 of ASTM E1249-00 (2005), the DUT's semiconductor chip plane was perpendicular to the incident radiation beam.
- 12. Filter box: a DMEA Dose Enhancement Chamber (DEC) was used for all testing/dosimetry involved with this experiment. The DEC's Pb and Al layers are compliant with section 7.2.2 of ASTM E1249-00 (2005) with respect to thickness and geometry.



## Appendix D

Table D1: Pre-Irradiation Electrical Characteristics of Device-Under-Test

				T <sub>J</sub> = 2	5°C	SUB-	-55°C	≤ T <sub>J</sub> ≤ 150°C	SUB-	
SYMBOL	PARAMETER	CONDITIONS	NOTES	MIN TY	P MAX	GROUP	MIN	TYP MAX	GROUP	UNITS
V <sub>REF</sub>	Reference Voltage	$ 3V \leq (V_{IN} - V_{OUT}) \leq 40V, \\ 10mA \leq I_{OUT} \leq I_{MAX}, \ P \leq P_{MAX} $		1.20	1.30	1	1.20	1.30	2,3	V
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Line Regulation	$ 3V \leq (V_{IN} - V_{OUT}) \leq 40V, \\ I_{OUT} = 10mA $	2		0.02	1		0.05	2,3	%/V
$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	Load Regulation	$\begin{array}{l} 10mA \leq I_{OUT} \leq I_{MAX},  V_{OUT} \leq 5V \\ 10mA \leq I_{OUT} \leq I_{MAX},  V_{OUT} \geq 5V \end{array}$	2 2		15 0.3	1		50 1	2,3 2,3	mV %
	Thermal Regulation	20ms Pulse			0.07	1				%/W
	Ripple Rejection	V <sub>OUT</sub> = 10V, f = 120Hz, C <sub>ADJ</sub> = 0		65				65		dB
		$V_{OUT} = 10V, f = 120Hz,$ $C_{ADJ} = 10\mu F$	3	66			66			dB
I <sub>ADJ</sub>	Adjust Pin Current				100	1		100	2,3	μA
$\Delta I_{ADJ}$	Adjust Pin Current	$10\text{mA} \le I_{OUT} \le I_{MAX}$			5	1		5	2,3	μA
	Change	$\label{eq:controller} \begin{split} 2.5V &\leq (V_{IN} - V_{OUT}) \leq 40V, \\ I_{OUT} &= 10 mA \end{split}$			5	1		5	2,3	μА
I <sub>MIN</sub>	Minimum Load Current	$(V_{IN} - V_{OUT}) = 40V$			5	1		5	2,3	mA
	Current Limit	$(V_{IN} - V_{OUT}) \le 15V$ H Package K Package		0.5 1.5		1	0.5 1.5		2,3 2,3	A A
		(V <sub>IN</sub> - V <sub>OUT</sub> ) = 40V H Package K Package		0.15 0.30		1				A A
$\Delta V_{OUT} \over \Delta Temp$	Temperature Stability	$-55^{\circ}\text{C} \le \text{T}_{\text{J}} \le 150^{\circ}\text{C}$						1		%
$\Delta V_{OUT} \over \Delta Time$	Long Term Stability	T <sub>A</sub> = 125°C	3					1		%
en	RMS Output Noise	$10Hz \le f \le 10kHz$		0.00	1					%
$\theta_{JC}$	Thermal Resistance (Junction to Case)	H Package K Package	3		15 3					°C/W



Table D2: Post-Irradiation Electrical Characteristics of Device-Under-Test

SYMBOL	PARAMETER	CONDITIONS	NOTES	10KR Min	AD(Si) Max	20KR/ MIN	AD(Si) Max	50KR Min	AD(Si) Max	100KF MIN	RAD(Si) Max	UNITS
V <sub>REF</sub>	Reference Voltage	$\begin{aligned} 3V &\leq (V_{IN} - V_{OUT}) \leq 40V, \\ 10mA &\leq I_{OUT} \leq I_{MAX},  P \leq P_{MAX} \end{aligned}$		1.20	1.30	1.20	1.30	1.20	1.30	1.20	1.30	V
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Line Regulation	$3V \le (V_{IN} - V_{OUT}) \le 40V, I_{OUT} = 10mA$	2		0.02		0.02		0.02		0.03	%/V
$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	Load Regulation	$\begin{array}{l} 10\text{mA} \leq I_{OUT} \leq I_{MAX},  V_{OUT} \leq 5V \\ 10\text{mA} \leq I_{OUT} \leq I_{MAX},  V_{OUT} \geq 5V \end{array}$	2 2		36 0.72		42 0.84		48 0.96		60 1.20	mV %
I <sub>ADJ</sub>	Adjust Pin Current				100		100		100		100	μA
$\Delta I_{ADJ}$	Adjust Pin Current	$10\text{mA} \le I_{OUT} \le I_{MAX}$			5		5		5		5	μA
	Change	$3V \le (V_{IN} - V_{OUT}) \le 40V$ , $I_{OUT} = 10mA$			5		5		5		5	μА
I <sub>MIN</sub>	Minimum Load Current	$(V_{IN} - V_{OUT}) = 40V$			5		5		5		5	mA
	Current Limit	(V <sub>IN</sub> − V <sub>OUT</sub> ) ≤ 15V H Package K Package		0.5 1.5		0.5 1.5		0.5 1.5		0.5 1.5		A
		(V <sub>IN</sub> - V <sub>OUT</sub> ) = 40V H Package K Package		0.15 0.30		0.15 0.30		0.15 0.30		0.15 0.30		A A

Note 1: Unless otherwise specified, these specifications apply for  $V_{IN} - V_{OUT} = 5V$ ; and  $I_{OUT} = 0.1A$  for the H package (TO-39) and  $I_{OUT} = 0.5A$  for the K package (TO-3) package. Although power dissipation is internally limited, these specifications are applicable for power dissipations of 2W for the TO-39 and 20W for the TO-3.  $I_{MAX}$  is 0.5A for the TO-39 and 1.5A for the TO-3.

**Note 2:** Regulation is measured at a constant junction temperature using pulse testing with a low duty cycle. Changes in output voltage due to heating effects are covered under the specification for thermal regulation.

**Note 3:** Guaranteed by design, characterization or correlation to other tested parameters.

Note 4:  $T_J = 25$ °C unless otherwise noted.